LAB04 ekstras

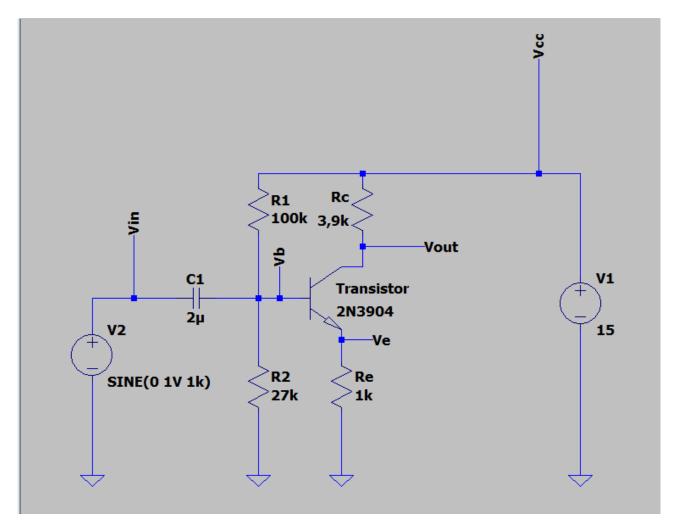
Task 1:

nPn

Components:

- V1+15 VDC
- Re 1k ohm
- Rc 3,9k ohm
- R1 100k ohm
- R2 27k
- C1 2uF
- nPn 2N3904
- Rb 10k ohm
- V2 Sine
 - o Amplitude 1V
 - o Offset 0V
 - o Frequency 1k Hz

Circuit:



Calculations:

Rth(Rb) = R1*R2/R1+R2 => 100k ohm*27k ohm/100k ohm + 27k ohm = 21 259,8 ohm

Vth(Vb) = (R2/R1+R2) *Vcc => (27k ohm/100k ohm + 27k ohm) *15 VDC = 3.188 VDC

Ib = Vth/Rth => 3,188 V/21 259,8k ohm = 149,954 uA

Ie = Vth-Vbe/Re+Rth/B => (3.188 VDC-0,7 V) / (1k ohm+21 259,8k ohm/100) = 2,052 mA

Ic = Ie => 2,052 mA

Ve = Ie*Re => 2,052 mA*1k ohm = 2,052 V

Vb = Ve+ 0,7 V => 2,052 V + 0,7V = 2,752 V

Vout = Vcc-Ic*Rc => 15 VDC - 2,052 mA*3,9k ohm = 6,99 V

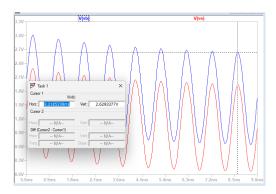
Vce = Vc - Ve => 6,99 V - 2,052 V = 4,945 V

Av = Vc/Vb => 6,99 V/2,752 V = 2,5-kertainen (AC voltage gain between base and collector.)

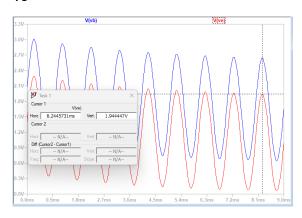
Av = 25mA / Ie, The 25 mV value is typically used as a rough approximation for the thermal voltage (Vt) at room temperature (25°C) in small-signal models of transistors. => 25mA / 2,052mA = 12,83 ohm

Simulations

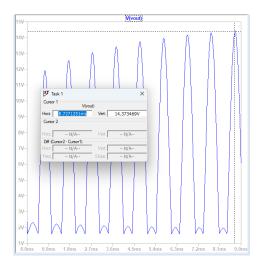
Vb



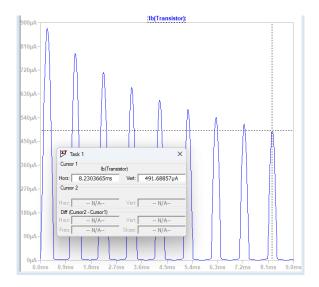
Ve



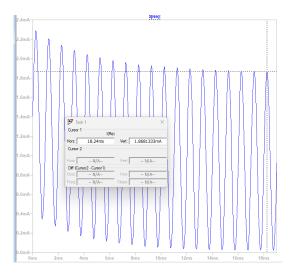
Vout



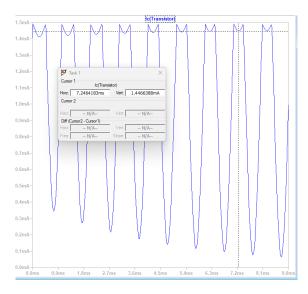
lb



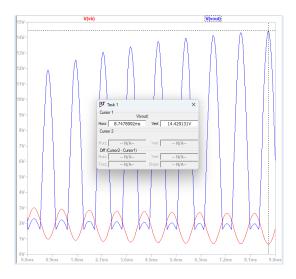
le



lc



Av (AC gain)



Conclusion:

Simulation data seems to correspond quite accuratly calculations. Only visible difference is output Vout. Vout seems to be almost double in simulation. Ic and Vout shape also raises questions. Mostly why the two signals start to follow up collector signal when on the same level. (?)

Circuit seems to create considerable voltage gain which very small (uA) current. In this sense, the circuit could be implemented physically for further testing.